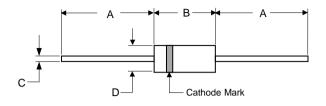


1SS133 Silicon Epitaxial Planar Switching Diode

Features

- * Glass sealed envelope
- * High speed
- * High reliability
- * High-speed switching









DO-35						
DIM	INCHES		MM			
	MIN	MAX	MIN	MAX		
Α	1.083		27.50			
В		0.154		3.90		
С		0.020		0.50		
D		0.075		1.90		

Maximum Ratings (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Value	Unit	
Peak Reverse Voltage	VRM	90	V	
DC Reverse Voltage	Vr	80	V	
Average Rectified Forward Current	lf(AV)	130	mA	
Peak Forward Current	Іғм	400	mA	
Surge Forward Current at t < 1 s	IFSM	600	mA	
Power Dissipation	Ptot	300	mW	
Junction Temperature	Tj	175	$^{\circ}\!\mathbb{C}$	
Storage Temperature Range	Tstg	- 65 to + 175	$^{\circ}\!\mathbb{C}$	

Electrical Characteristics (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Max.	Unit
Forward Voltage at I _F = 100 mA	VF	1.2	V
Reverse Current at $V_R = 80 \text{ V}$	lr	0.5	μΑ
Capacitance between Terminals at $V_R = 0.5 \text{ V}$, $f = 1 \text{ MHz}$	Ст	2	pF
Reverse Recovery Time at IF = 10 mA, $V_R = 6 V$, $R_L = 50 \Omega$	trr	4	ns

Version: 6.1 www.jgdsemi.com



1SS133 Silicon Epitaxial Planar Switching Diode

Ratings and Characteristic Curves

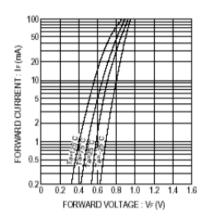


Fig. 1 Forward characteristics

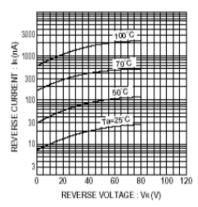


Fig. 2 Reverse characteristics

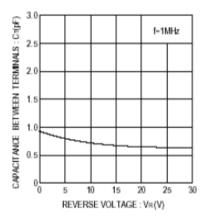


Fig. 3 Capacitance between terminals characteristics

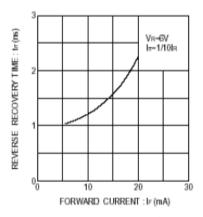


Fig. 4 Reverse recovery time characteristics

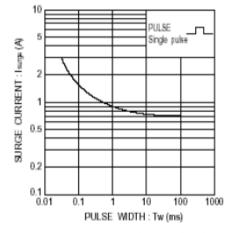


Fig.5 Surge current characteristics

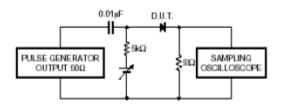


Fig. 6 Reverse recovery time (t_r) measurement circuit

Version: 6.1 www.jgdsemi.com



1SS133 Silicon Epitaxial Planar Switching Diode

Ordering Information

Part No.	Package	Packing Code	Packing
1SS133	DO-35	A50	5000pcs/Ammo

Disclaimer

Specifications of the products displayed herein are subject to change without notice. JGD or anyone on its behalf, assumes no responsibility or liability for any errors inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied,to any intellectual property rights is granted by this document. Except as provided in JGD's terms and conditions of sale for such products, JGD assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of JGD products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or seling these products for use in such applications do so at their own risk and agree to fully indemnify JGD for any damages resulting from such improper use or sale.

Version: 6.1 www.jgdsemi.com